



1.8V Low Power Dual RS-232 Transceiver Support 1.65V to 5V IO

UM3122EEQA

General Description

The UM3122EEQA is a two-driver and two-receiver RS-232 interface device, with split supply pins for mixed-voltage operation. All RS-232 inputs and outputs are protected to ± 15 kV using the IEC 61000-4-2 Air-Gap Discharge method, ± 8 kV using the IEC 61000-4-2 Contact Discharge method, and ± 8 kV using the Human-Body Model. The charge pump requires five small 0.1µF capacitors for operation from as low as a 1.8V supply. The UM3122EEQA is capable of running at data rates up to 1000 kbps, while maintaining RS-232 compatible output levels. The UM3122EEQA has a unique V_L pin that allows operation in mixed-logic voltage systems. Both driver in (D_{IN}) and receiver out (R_{OUT}) logic levels are pin programmable through the V_L pin. This eliminates the need for additional voltage level shifter while interfacing with low-voltage microcontrollers or UARTs. Auto Powerdown Plus automatically places the device in a low power mode when the device has not received or transmitted data for more than 30 seconds. This feature makes this device a very attractive option for battery powered or other power sensitive applications.

Applications

- Remote Radio Unit (RRU)
- Base Band Unit (BBU)
- Electronic Point of Sale (EPOS)
- Diagnostics & Data Transmission
- Battery-Powered Equipment

Features

- Extended V_{CC} operating nodes: 1.8V, 3.3V, or 5.0V
 - Unique Tripler Charge Pump Architecture Enables Low V_{CC} of 1.8V While Maintaining Compatibility with 3.3V and 5V Supplies
- Integrated Level-Shifting Functionality Eliminates the Need for External Power or Additional Level Shifter While Interfacing with Low-Voltage MCUs
- Enhanced ESD Protection on R_{IN} Inputs and D_{OUT} Outputs
 - ±15kV IEC 61000-4-2 Air-Gap Discharge
 - ±8kV IEC 61000-4-2 Contact Discharge
 - ±8kV Human-Body Model
- Specified 1000 kbps Data Rate
- Auto Powerdown Plus Feature
- Low 0.5uA Shutdown Supply Current
- Meets or Exceeds Compatibility Requiremen of RS-232 Interface

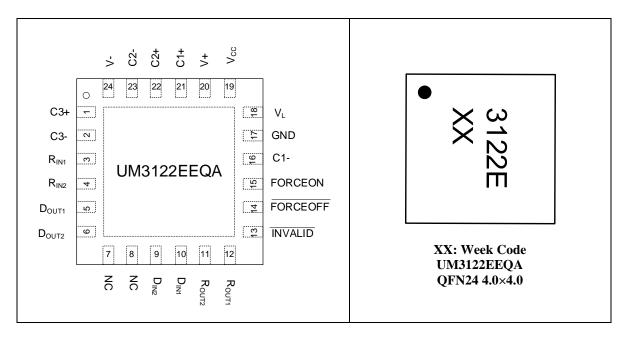


Ordering Information

Part Number	Temp. Range	Marking Code	Package Type	Shipping Qty
	4000 + 10500	21005		3000pcs/13Inch
UM3122EEQA	-40° C to $+105^{\circ}$ C	3122E	QFN24 4.0×4.0	Tape & Reel

Pin Configurations

Top View





Pin Description

Pin No.	Pin Name	Function
1	C3+	Positive terminal of voltage-tripler charge-pump capacitor (Not needed for V _{CC} 3V to 5.5V)
2	С3-	Negative terminal of voltage-tripler charge-pump capacitor (Not needed for V _{CC} 3V to 5.5V)
3	R _{IN1}	RS-232 Receiver Input
4	R _{IN2}	RS-232 Receiver Input
5	D _{OUT1}	RS-232 Driver Output
6	D _{OUT2}	RS-232 Driver Output
7	NC	Factory pin, can be unconnected or connected to GND
8	NC	Factory pin, can be unconnected or connected to GND
9	D _{IN2}	RS-232 Driver Input
10	D _{IN1}	RS-232 Driver Input
11	R _{OUT2}	RS-232 Receiver Output
12	R _{OUT1}	RS-232 Receiver Output
13	INVALID	Invalid Output Pin
14	FORCEOFF	Auto Powerdown Control input (Refer to Truth Table)
15	FORCEON	Auto Powerdown Control input (Refer to Truth Table)
16	C1-	Negative terminal of voltage-doubler charge-pump capacitors (required)
17	GND	Ground
18	V _L	Logic-level supply. All CMOS inputs (D _{IN}) and outputs (R _{OUT}) are referenced to this supply
19	V _{CC}	1.8V or 3V to 5V Supply Voltage Input
20	V_+	Positive charge pump storage capacitor (required)
21	C1+	Positive terminal of voltage-doubler charge-pump capacitor (required)
22	C2+	Positive terminal of voltage-doubler charge-pump capacitor (required)
23	C2-	Negative terminal of voltage-doubler charge-pump capacitors (required)
24	V-	Negative charge pump storage capacitor (required)



Absolute Maximum Ratings (Note1)

Symbol	Parameter	Value	Unit
V _{CC}	Charge pump power supply	-0.3 to +6	V
VL	Logic Power Supply	-0.3 to +6	V
V_+	Positive storage capacitor voltage+	-0.3 to +7	V
V_	Negative storage capacitor voltage	-7 to +0.3	V
D _{IN}	Voltage on D _{IN}	-0.3 to (V _L +0.3)	V
R _{IN}	$(0\Omega \text{ series resistance})$ ($\geq 250\Omega \text{ series resistance})$	±20 ±25	- V
D _{OUT}	Output voltage	V_{-} -0.3 to V_{+} + 0.3	V
R _{OUT}	Output voltage	-0.3 to (V _L +0.3)	V
$V_+ + V $ (Note2)		13	
FORCEOFF	Input voltage	-0.3 to +6	V
FORCEON	Input voltage	-0.3 to +6	V
TJ	Junction temperature	150	°C
T _{stg}	Storage temperature range	-65 to 150	°C

Note1: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Thermal Characteristics

Symbol	Thermal Metric	Value	Unit
θ_{JA}	Junction-to-ambient thermal resistance	34.2	°C/W
θ_{JC}	Junction-to-case thermal resistance	27.2	C/ W

Note2: V_+ and V_- can have maximum magnitudes of 7V, but their absolute difference cannot exceed 13V.



Recommended Operating Conditions

Parameter	Symbol	Condition	Min	Тур	Max	Unit
		Tripler Mode	1.65	1.8	2	
Charge pump power supply	V _{CC}	Doubler Mode	3	3.3	3.6	V
		Doubler Mode	4.5	5	5.5	
Logic power supply	V_L		1.65		V _{CC}	V
RS-232 Receiver interface	R _{IN}		-15		15	V
RS-232 Transmitter interface	D _{OUT}		-7		7	V
GPIO Input logic	V _{IL}	$V_L = 5.0 V$	0		1.7	
threshold low $(D_{IN}, \overline{FORCEOFF},$		$V_L = 3.3V$	0		1.1	v
FORCEON)		$V_L = 1.8 V$	0		0.6	
GPIO Input logic		$V_L = 5.0V$	3.3		V_L	
threshold high	\mathbf{V}_{IH}	$V_{L} = 3.3V$	2.2		V_L	v
$(D_{IN}, FORCEOFF, FORCEON)$		$V_L = 1.8V$	1.2		V_L	
R _{OUT} disabled	V _{OZ}	$\overline{\text{FORCEOFF}} = 0\text{V}$	0		V _L	v
Operating temperature			-40		105	°C



Electrical Characteristics

 $V_{CC} = V_L = (1.65 \text{ V to } 2.0 \text{ V}) \& (3.0 \text{ V to } 5.5 \text{ V}), T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$ (unless otherwise noted). Typical data is $T_A = 25^{\circ}\text{C}, V_{CC} = V_L = 3.3 \text{ V}$ (unless otherwise noted).

	1	cal Characteristic						
Parameter	Symbol		onditio		Min	Тур	Max	Unit
		$D_{IN1} = GND \text{ or}$ $V_L;$	to 2.0V			1.0	1.9	
Static	$I_{CC}~({\rm static})$	$D_{IN2} = GND \text{ or}$ $V_L,$ $\overline{CODCEODE}$	No load	V _{CC} = 3.0V to 3.6V		0.7	1.4	mA
		$FORCEOFF = V_L$ $FORCEON = V_L$	load	V _{CC} = 4.5V to 5.5V		0.8	1.9	
off	$I_{CC \ (off)}$	FORC	EOFF=	GND		0.4	10	μΑ
R _{IN} positive voltage threshold for INVALID output change	V _{IT+}				0.3		2.4	v
R _{IN} negative voltage threshold for INVALID output change	V _{IT-}	$\mathbf{R}_{\mathbf{IN1}}=\mathbf{R}_{\mathbf{IN2}}$			-2.4		-0.3	
INVALID high-level output voltage	V _{OH}	$I_{OH} = -1 \text{ mA}, \text{ FORCEON} = \text{GND},$ $\overline{\text{FORCEOFF}} = V_L$			V _L -0.4	V _L -0.08	V_L	v
INVALID low-level output voltage	Vol	$I_{OL} = 1.6 \text{ mA}, \text{ FORCEON} = \text{GND},$ $\overline{\text{FORCEOFF}} = V_L$			0	0.06	0.4	v
Driver Electric	al Charact	eristics						
Output voltage	V		All driver outputs loaded with 3 k Ω to ground C3 = 100 nF, V _{CC} = 1.8 V		±4.25	±4.7		V
swing	V _{OUT}		the state of the		±5	±5.4		V
Output short-circuit	Ios	$V_{\text{DOUT}} = 0$				±60	mA	
Input leakage current		$D_{IN} = GND$ to V_I to V_L ; FORC				0	±10	μΑ



Electrical Characteristics (continued)

 $V_{CC} = V_L = (1.65 \text{ V to } 2.0 \text{ V}) \& (3.0 \text{ V to } 5.5 \text{ V}), T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C} \text{ (unless otherwise noted)}.$ Typical data is $T_A = 25^{\circ}\text{C}$, $V_{CC} = V_L = 3.3 \text{ V}$ (unless otherwise noted).

Receiver Electr	ical Chara	octeristics			•		1
Parameter	Symbol	Con	Min	Тур	Max	Unit	
Output leakage current	$I_{\rm off}$	R _{OUT} , rece	ives disabled		±0.01	±10	μΑ
Output voltage low	V_{OL}	I _{out} =2	2.0mA		0.04	0.3	V
Output voltage high	V _{OH}	I _{out} = -	2.0mA	V _L -0.3	V _L -0.04		V
T			V _L =5	0.8	1.5		
Input threshold low	V _{IT-}	$T_A=25^{\circ}C$	$V_L=3.3V$	0.7	1.1		V
			$V_L=1.8V$	0.6	0.7		
T (1 1 1 1			$V_L=5V$		2.0	2.4	
Input threshold high	$V_{\rm IT+}$	V_{IT+} $T_A=25^{\circ}C$	V _L =3.3V		1.5	2.4	V
			V _L =1.8V		0.9	1.4	
		V _L =5V		0.45			
Input hysteresis	V_{hys}	$T_A=25^{\circ}C$	V _L =3.3V		0.35		V
			V _L =1.8V		0.26		
Input resistance		$T_{A} = -40$	to 105 °C	3	5	7	kΩ
Driver Switchin	g Charact	teristics					
Maximum data		$R_L = 3 k\Omega, C_L = 5$	500 pF (one driver)	1000			1.1
rate		$R_L = 3 k\Omega, C_L = 1$	000 pF (one driver)	500			kbps
Time-to-exit powerdown		V _{DOUT}	> 3.7 V		30	150	μs
Driver skew (Note1)	t _{PHL} — t _{PLH}	$R_L =$	3 kΩ	0	50	100	ns
			$\label{eq:VCC} \begin{split} V_{\rm CC} &= 1.8 V, \\ C_{\rm L} &= 200 \ p F \end{split}$		33		
		$P = 2 k O t_{2} 7$	$\label{eq:VCC} \begin{split} V_{CC} &= 1.8 V, \\ C_L &= 1000 p F \end{split}$		25		
Transition-		$R_L = 3 k\Omega \text{ to } 7$ $k\Omega, T_A = 25^{\circ}C$ Measured from	$\label{eq:Vcc} \begin{split} V_{CC} &= 3.3 \ V, \\ C_L &= 200 \ pF \end{split}$		38		V /
Region slew rate		3 V to -3V or $-3 V \text{ to } 3 V$	$V_{CC} = 3.3 V,$ $C_L = 1000 pF$		28		V/µs
		01 5 7 10 5 7	$V_{CC} = 5 \text{ V},$ $C_L = 200 \text{ pF}$		41		
			$V_{CC} = 5 \text{ V},$ $C_{L} = 1000 \text{ pF}$		30		



Electrical Characteristics (continued)

 $V_{CC} = V_L = (1.65 \text{ V to } 2.0 \text{ V}) \& (3.0 \text{ V to } 5.5 \text{ V}), T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C} \text{ (unless otherwise noted)}.$ Typical data is $T_A = 25^{\circ}\text{C}, V_{CC} = V_L = 3.3 \text{ V}(\text{unless otherwise noted}).$

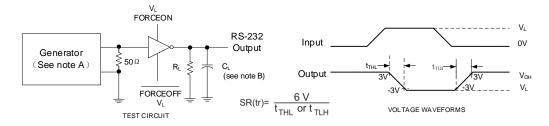
Parameter	Symbol	Conditio	n	Min	Тур	Max	Unit
Receiver propagation delay, high to low	t _{PHL}	Receiver input to receiver output			0.15	0.4	μs
Receiver propagation delay, low to high	t _{PLH}	$C_L = 150$	-		0.15	0.4	μs
Receiver skew	t _{PHL} –t _{PLH}				50	300	ns
Receiver output enable time	t _{en}	From FORCEOFF	to $R_{OUT} = V_1/2$		200	400	ns
Receiver output disable time	t _{dis}	$C_{L} = 150 \text{ pF}, \text{ R}$			200	400	ns
Power and Statu	s Switchin	g Characteristics					
Propagation delay time, low to high level output	t _{valid}				1		μs
Propagation delay time, high to low level output	t _{invalid}				30		μs
Receiver or driver edge to auto powerdown plus	t _{dis}			15	30	60	S
ESD							
		Human body model (HBM), per ANSI/ESDA/JEDEC	All pins except RS-232 bus	±2000			
Electrostatic	V _(ESD)	JS-001, all pins (Note2)	RS-232 bus pins		±8000		V
discharge		IEC 61000-4-2 Air-Gap Discharge	RS-232 bus		±15000		
		IEC 61000-4-2 Contact Discharge	pins	±8000			

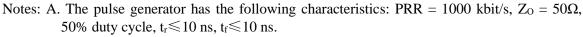
Note1: Driver skew is measured at the driver zero crosspoint.

Note2: JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.



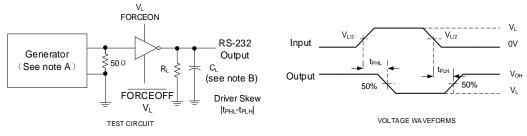
Parameter Measurement Information





B. C_L includes probe and jig capacitance.

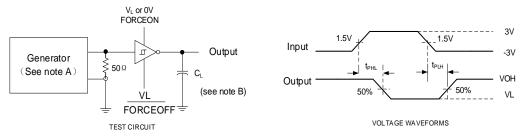
Figure 1. Driver Slew Rate



Notes: A. The pulse generator has the following characteristics: PRR = 1000 kbit/s, $Z_0 = 50\Omega$, 50% duty cycle, $t_r \leq 10$ ns, $t_f \leq 10$ ns.

B. C_L includes probe and jig capacitance.

Figure 2. Driver Pulse Skew



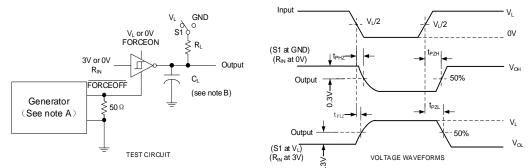
Notes: A. The pulse generator has the following characteristics: $Z_0 = 50\Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

B. C_L includes probe and jig capacitance.

Figure 3. Receiver Propagation Delay Times



Parameter Measurement Information (continued)



- Note: A. The pulse generator has the following characteristics: $Z_0 = 50\Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.
 - B. C_L includes probe and jig capacitance.
 - C. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - D. t_{PLZ} and t_{PHZ} are the same as t_{en} .

Figure 4. Receiver Enable and Disable Times

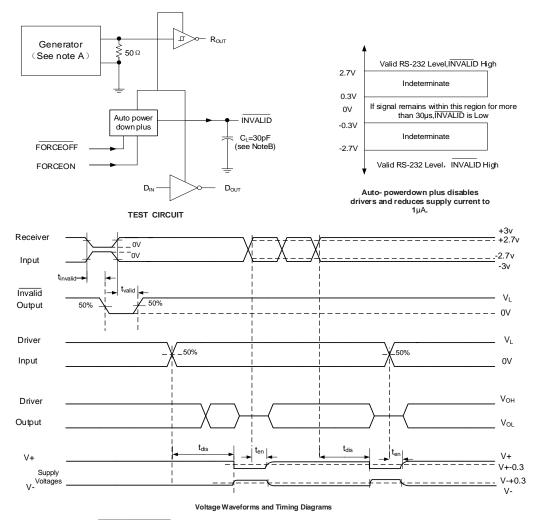
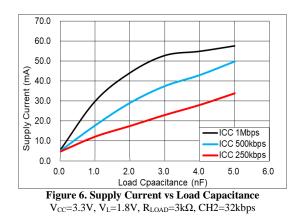


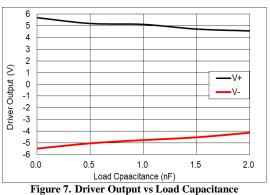
Figure 5. INVALID Propagation-Delay Times and Supply-Enabling Time

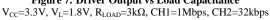




Typical Characteristics







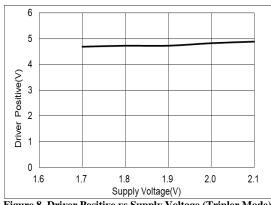
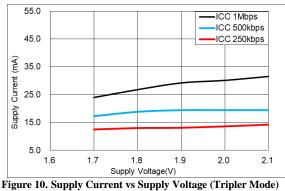
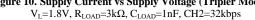
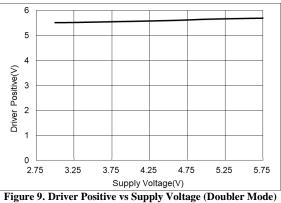
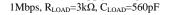


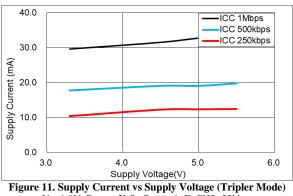
Figure 8. Driver Positive vs Supply Voltage (Tripler Mode) $1Mbps, R_{LOAD}=3k\Omega, C_{LOAD}=560pF$















Detailed Description

Overview

The UM3122EEQA is an upgrade to standard RS-232 transceivers, offering compatibility with modern system needs like 1.8V GPIO capability, enhanced ESD & ultralow stand-by current. The majority of RS-232 transceivers with 1.8V GPIO compatibility require a logic supply pin for the I/O translation, in addition to a minimum 3.3V V_{CC} for all of the other active circuitry on the chip. Unlike these transceivers, UM3122EEQA can operate with both V_L and V_{CC} equal to 1.8V. When V_{CC}=3.0V to 5.5V, the charge pump will sense V_{CC} and switch to doubler mode. C1 & C2 are the necessary flying capacitors, C3 is not needed, and the charge pump outputs V₊ & V₋ will regulate to ~+/-5.4V. When V_{CC}=1.65V to 2.0V, the charge pump will sense V_{CC} and switch to tripler mode. C1, C2&C3 are all necessary, and the charge pump outputs V₊ & V₋ will regulate to ~+/-2.65*V_{CC} from V_{CC}=1.65V to 2.0V.

With many modern applications expanding into products that use UM3122EEQA as a backup communication protocol, it is important for the transceiver to have efficient standby operation. In order to accommodate this, Auto Powerdown Plus has been integrated to shut-off all active circuitry, allowing UM3122EEQA to achieve an $I_{\rm off}$ of 1uA.

In order to comply with common interface system needs and environments, the RS-232 receive and transmit I/O pins comply with IEC 61000-4-2 ratings.

Detailed Functional Block Diagram

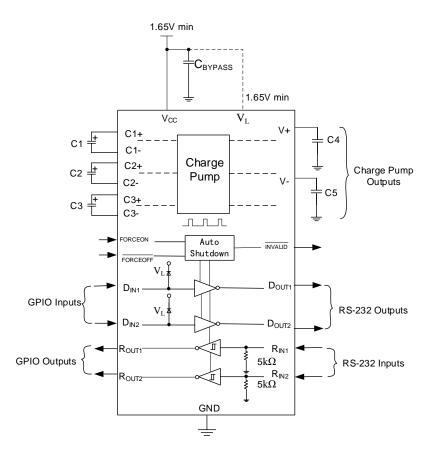


Figure 12. Schematic



Feature Description

Charge Pump

The internal power supply consists of a regulated auto-sensing charge pump that provides RS-232 compatible output voltages, over the 1.65V to 2.0V and 3.0V to 5.5V V_{CC} ranges. The charge pump operates in two modes to efficiently accommodate low voltage (1.8V) and higher voltage (3.3V & 5.0V) supplies.

Doubler Mode: The charge pump requires two flying capacitors (C1, C2) and reservoir capacitors (C4, C5) to generate the V_+ and V- supplies of approximately $\pm 5.4V$ when V_{CC} is greater than 3 V. When V_{CC} is >2.9V, UM3122EEQA will sense the supply voltage level and switch the charge pump to a doubler. Hence, no need for a third flying capacitor. C3+&C3- pins can be left open for proper operation. If a capacitor is placed between C3+&C3-, the charge pump will ignore this capacitor and still behave as a doubler. For capacitor choice recommendations, please refer to Capacitor Selection Table.

Tripler Mode: The charge pump requires three flying capacitors (C1, C2&C3) and reservoir capacitors (C4, C5) to generate the V₊ and V- supplies of approximately $\pm 2.65 \text{*V}_{CC}$ when V_{CC} is greater than 1.65V. When V_{CC} is < 2.1V, UM3122EEQA will sense the supply voltage level and switch the charge pump to a tripler.

Drivers

The drivers are inverting level transmitters that convert TTL or CMOS logic levels to RS-232 levels. For V_{CC} =3.0V to 5.0V, the RS-232 output voltage swing is typically ±5.4V fully loaded and ±5 V minimum fully loaded. For V_{CC} = 1.8V, the RS-232 output voltage swing is typically ±.4.7V fully loaded and ±4.25V minimum fully loaded. The driver outputs are protected against indefinite short-circuits to ground without degradation in reliability. These drivers are compatible with RS-232 logic levels and all previous RS-232 versions. Unused driver inputs should be connected to GND or V_{CC} .

Receivers

The receivers convert EIA/TIA-232 levels to TTL or CMOS logic output levels. Receivers have an inverting output that can be disabled by using the $\overline{\text{FORCEOFF}}$ pin. Receivers remain active when the Auto Powerdown Plus circuitry autonomously enters a low power state. See Auto

Powerdown Plus for more information on the Auto Powerdown mode. If the FORCEOFF pin is manually set low, the receivers will be disabled and put into 3-state mode. In either of these Powerdown modes, the device will typically consume about 0.5 uA. The truth table logic of the UM3122EEQA driver and receiver outputs can be found in Device Functional Modes. Since receiver input is usually from a transmission line where long cable lengths and system interference can degrade the signal, the inputs have a typical hysteresis margin of 300 mV. This ensures that the receiver is virtually immune to noisy transmission lines. Should an input be left unconnected, an internal $5k\Omega$ pull-down resistor to ground will commit the output of the receiver to a HIGH state.

Auto Powerdown Plus

Powerdown is engaged in two separate cases: automatically, when no activity has occurred for a

period of time, and manually, using the FORCEOFF device pin.

Automatic Powerdown: Auto Powerdown Plus is enabled when FORCEON is set LOW and



FORCEOFF is set HIGH. Using UM3122EEQA's integrated edge detection circuitry and timer, the device can sense when there is no activity on the driver or receiver inputs for 30 seconds. When this condition is sensed by the device, it automatically shuts the charge pump off, reducing supply current to 0.5μ A. When a valid transition is sensed on one of the driver or receiver inputs, the charge pump turns back on and UM3122EEQA exits powerdown. The typical time to exit powerdown is typically in 30 us, but can be as long as 150 us. As a result, the system saves power without requiring any software control. Device Functional Modes summarizes the operating modes in truth table form. While in the low power mode with Automatic Powerdown enabled

(FORCEOFF = HIGH and FORCEON = LOW), the receiver inputs are still enabled.

Manual Powerdown:

The device can be manually powered down by externally setting FORCEOFF pin to low logic level. Both the drivers and receivers will be powered off. Device Functional Modes summarizes the operating modes in truth table form.

Forced On: If the FORCEOFF and FORCEON pins are both set HIGH, the device will power on with Auto Powerdown Plus disabled. Both the drivers and receiver will be active regardless of inactivity. Because Powerdown is autonomous, FORCEON can be used ensure drivers are ready for new data transmission if the time since last transmission (or receive data) was more than 15 seconds. Device Functional Modes summarizes the operating modes in truth table form.

		Inputs		Outputs	
D _{IN}	FORCEON	FORCEOFF	$\begin{array}{l} Time \ elapsed \\ since \ last \ R_{IN} \ or \\ D_{IN} \ transition \end{array}$	D _{OUT}	Driver status
X	X	L	Х	Z	Powered off
L	Н	Н	Х	Н	Normal operation with auto-powerdown plus
Н	Н	Н	Х	L	disabled
L	L	Н	<30s	Н	Normal operation with auto-powerdown plus
Н	L	Н	<30s	L	enabled
L	L	Н	>30s	Z	Normal operation with auto-powerdown plus
Н	L	Н	>30s	Z	feature

Device Functional Modes

Each Driver (Note1)

Note1: H = high level, L = low level, X = irrelevant, Z = high impedance (off), 30s is typical inactivity time.



Each Receiver (Note1)

	Inp	uts	Outputs	
R _{IN}	FORCEOFF	Time elapsed since last $R_{\rm IN}$ or $D_{\rm IN}$ transition	R _{OUT}	Receiver status
Х	L	Х	Z	Powered off
L	Н	Х	Н	Normal operation with auto-powerdown plus
Н	Н	Х	L	disabled
Open	Н	Х	Н	Normal operation with auto-powerdown plus enabled

Note1: H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off.

Invalid Status Truth (Note1)

	Inputs					
R _{IN1} , R _{IN2}	FORCEON	FORCEOFF	Time elapsed since last R_{IN} or D_{IN} transition	Invalid		
Any L or H	Х	Х	Х	Н		
All Open	Х	X	Х	L		

Note1: H = high level, L = low level, X = irrelevant, Z = high impedance (off), 30s is typical inactivity time.

Applications Information

UM3122EEQA is used to communicate between two electrical units on separate PCBs across cables <40 ft. Common UM3122EEQA cables are RJ45, DB9 & DB25.Typical 1.8V Application is shown in the figure below.

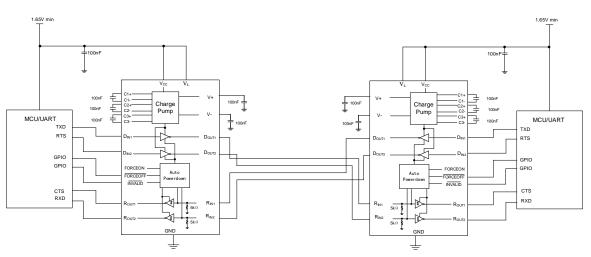


Figure 13. Typical 1.8V Application



Data-Rate and Cable Length

RS-232 intended is for short range data transmission. The rise time for RS-232 driver edges is slow enough that the data cable appears as a capacitor instead of a transmission line impedance. The elapsed time for one bit of data far exceeds the transit time of any practical RS-232 cable length. The capacitance of the cable is the limiting factor. Therefore, the capacitance per foot (or meter) of the cable is important if long data cables are used. Capacitance slows the rise and fall time of the signal. For low data rates, the delay is insignificant. However, high data rates will have reduced percentage of time that the output is at V_{OL} or V_{OH} and more time in the transitions.

The timing of the UART (universal asynchronous receiver/transmitter) must sample the signal at the right time to coincide with V_{OL} and V_{OH} plateaus. At some point data reliability will be impacted. There are no hard limits for cable capacitance and data rate.

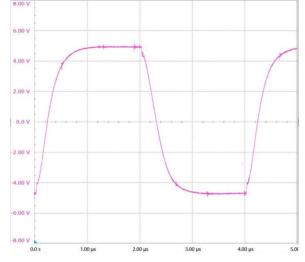


Figure 14. Typical Waveform with Capacitive Load

 $V_{CC} = 3.3 \text{ V}, R_{LOAD} = 3 \text{ k}\Omega$, Date Rate = 500kbps, C=2nF

The maximum cable length depends on the cable used (pf/ft), data rate, timing of receiving UART, system tolerance to data errors.

Capacitor Selection

The capacitor type used for C1–C5 is not critical for proper operation; polarized or non-polarized capacitors can be used, though lower ESR capacitors are preferred. The charge pump requires 0.1 μ F capacitors for V_{CC} =1.8V or V_{CC} = 3.3V operation. For other supply voltages, see the Capacitor Selection Table for required capacitor values. Do not use values smaller than those listed in Capacitor Selection Table. Increasing the capacitor values, except for C1, reduces ripple on the transmitter outputs and slightly reduces power consumption. C2, C3, C4 and C5 can be increased without changing C1's value. However, do not increase C1 without also increasing the values of C2, C3, C4, C5, C_{BYPASS1}, and C_{BYPASS2} to maintain the proper ratios (C1 to the other capacitors). When using the minimum required capacitor values, make sure the capacitor value does not degrade excessively with temperature. If in doubt, use capacitors with a larger nominal value. The capacitor's equivalent series resistance (ESR) usually increases at low temperatures.

For best charge pump efficiency locate the charge pump and bypass capacitors as close as possible to the IC. Surface mount capacitors are best for this purpose. Using capacitors with lower equivalent series resistance (ESR) and self-inductance, along with minimizing parasitic PCB trace inductance will optimize charge pump operation. Designers are also advised to consider that capacitor values may shift over time and operating temperature.



$V_{CC} = V_L$	C1 Capacitor Value	C2 Capacitor Value	C3 Capacitor Value	C4 Capacitor Value	C5 Capacitor Value				
1.65 V to 2 V (Note1)	100 nF								
3.0 V to 3.6 V (Note1)	100 nF		100 nF or open	100)nF				
4.5 V to 5.5 V (Note1)	47 nF	330 nF	100 nF or open	330)nF				
3 V to 5.5 V (Note2)	47 nF	470 nF	100 nF or open	470)nF				

Note1: For optimized performance, we recommend using these configurations.

Note2: For applications where the V_{CC} variation is larger, this configuration is acceptable.

Application Curves

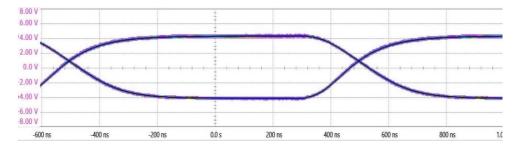


Figure 14.1 Mbps Eye Diagram, 2 V/div, 200 ns/ div $V_{CC} = 1.8$ V, $C_{LOAD} = 500$ pF, $R_{LOAD} = 3$ k Ω

Power Supply Recommendations

In most circumstances, a $0.1\mu F V_{CC}$ bypass capacitor and a $1\mu F V_L$ bypass capacitor are adequate. In applications that are sensitive to power-supply noise, use larger value V_{CC} bypass capacitor. There is no maximum limit for bypass capacitor. Place bypass capacitors as close to the IC as possible. It is not recommended to use this device when V_{CC} is powered and $V_L = 0$ V or floating for an extended period of time because operation is undefined. V_{CC} and V_L must be powered to guarantee charge pump operation. Also, to achieve full functionality as described in Specifications, it is recommended to not use a higher voltage on V_L than V_{CC} . Full functionality can be achieved when V_{CC} is greater than or equal to V_L .



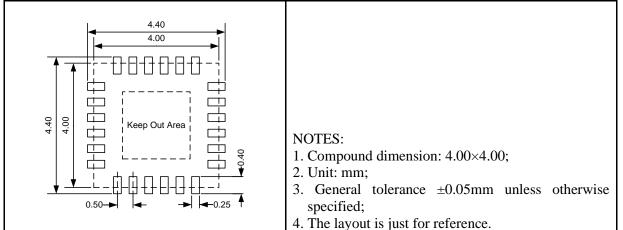
Package Information

UM3122EEQA: QFN24 4.0 × 4.0

Outline Drawing

	L L L L L L L L L L L L L L	DIMENSIONS						
		Symbol	MILLIMETERS			INCHES		
<mark>∢ D</mark>			Min	Тур	Max	Min	Тур	Max
Pin #1 ID		А	0.70	0.75	0.80	0.028	0.030	0.031
		A1	0.00	0.02	0.05	0.000	0.001	0.002
		A3	0.20REF		0.008REF			
		b	0.20	0.25	0.30	0.008	0.010	0.012
		D	3.90	4.00	4.10	0.154	0.157	0.161
		Е	3.90	4.00	4.10	0.154	0.157	0.161
Top View		D2	2.40	1	2.70	0.098	0.102	0.106
		E2	2.40	-	2.70	0.098	0.102	0.106
		e	0.40	0.50	0.60	0.016	0.020	0.024
Side View		K	0.20	-	-	0.008	-	-
		L	0.35	0.40	0.45	0.014	0.016	0.018

Land Pattern



Tape and Reel Orientation





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